



Freeform Search

Database:	US Pre-Grant Publication Full-Text Database
	US Patents Full-Text Database
	US OCR Full-Text Database
	EPO Abstracts Database
	JPO Abstracts Database
	Derwent World Patents Index
	IBM Technical Disclosure Bulletins

Term:	L6 and gate	 
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Display:	<input type="text" value="10"/>	Documents in Display Format:	<input type="text" value="-"/>	Starting with Number	<input type="text" value="1"/>
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Generate: ☐ Hit List ☒ Hit Count ☐ Side by Side ☐ Image

Search History

DATE: Tuesday, April 12, 2005 [Printable Copy](#) [Create Case](#)

<u>Set</u> <u>Name</u> side by side	<u>Query</u>	<u>Hit</u> <u>Count</u>	<u>Set</u> <u>Name</u> result set
<i>DB=PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD; PLUR=YES; OP=OR</i>			
<u>L7</u>	L6 and gate	387	<u>L7</u>
<u>L6</u>	L4 and nm	421	<u>L6</u>
<u>L5</u>	L4 and nm	421	<u>L5</u>
<u>L4</u>	L3 and (nitride with (thin or thick or thickness))	647	<u>L4</u>
<u>L3</u>	((ultra-small or minute or small\$2 or nano-scale) with grain\$1) and polysilicon and nitride	1146	<u>L3</u>
<u>L2</u>	L1 and polysilicon	73	<u>L2</u>
<u>L1</u>	(grain adj size) with nitride	1676	<u>L1</u>

END OF SEARCH HISTORY

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments
1	IS&R	L1	0	("(grainadjsize)withpolysilicon").PN.	USPAT; USOCR	2005/04/12 08:40	
2	BRS	L2	536	((grain adj size) with polysilicon)	USPAT	2005/04/12 08:41	
3	BRS	L3	295	L2 and gate and nitride	USPAT	2005/04/12 08:41	